Unit: mm

TOSHIBA Transistor Silicon NPN Epitaxial Type (PCT process)

# 2SC1815

# Audio Frequency General Purpose Amplifier Applications Driver Stage Amplifier Applications

• High voltage and high current: VCEO = 50 V (min),

IC = 150 mA (max)

• Excellent hFE linearity: hFE (2) = 100 (typ.)

at  $V_{CE} = 6 \text{ V}$ ,  $I_{C} = 150 \text{ mA}$ 

:  $h_{FE} (I_{C} = 0.1 \text{ mA})/h_{FE} (I_{C} = 2 \text{ mA})$ 

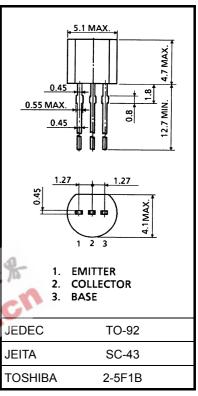
= 0.95 (typ.)

Low noise: NF = 1dB (typ.) at f = 1 kHz

• Complementary to 2SA1015 (O, Y, GR class)

## **Absolute Maximum Ratings (Ta = 25°C)**

| Characteristics             | Symbol           | Rating  | Unit |  |
|-----------------------------|------------------|---------|------|--|
| Collector-base voltage      | $V_{CBO}$        | 60      | V    |  |
| Collector-emitter voltage   | V <sub>CEO</sub> | 50      | V    |  |
| Emitter-base voltage        | V <sub>EBO</sub> | 5       | V    |  |
| Collector current           | Ic               | 150     | mA   |  |
| Base current                | ΙΒ               | 50      | mA   |  |
| Collector power dissipation | PC               | 400     | mW   |  |
| Junction temperature        | Tj               | 125     | °C   |  |
| Storage temperature range   | T <sub>stg</sub> | -55~125 | °C   |  |



Weight: 0.21 g (typ.)

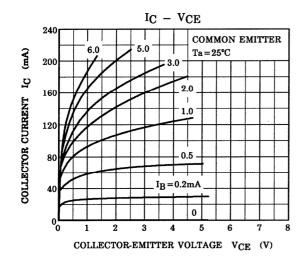
Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in

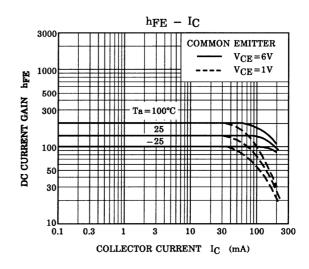
temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

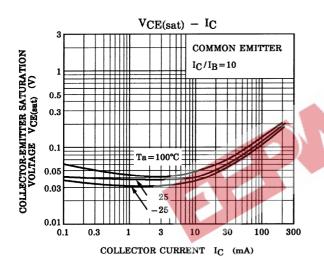
#### **Electrical Characteristics (Ta = 25°C)**

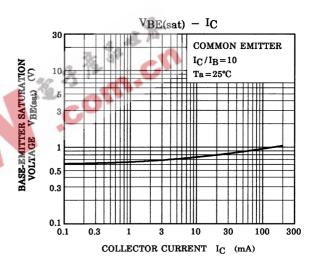
| Characteristics                      | Symbol                     | Test Condition  | Min | Тур. | Max  | Unit |
|--------------------------------------|----------------------------|---|-----|------|------|------|
| Collector cut-off current            | I <sub>CBO</sub>           | V <sub>CB</sub> = 60 V, I <sub>E</sub> = 0  | _   | _    | 0.1  | μА   |
| Emitter cut-off current              | I <sub>EBO</sub>           | V <sub>EB</sub> = 5 V, I <sub>C</sub> = 0   | _   | _    | 0.1  | μА   |
| DC current gain                      | h <sub>FE (1)</sub> (Note) | V <sub>CE</sub> = 6 V, I <sub>C</sub> = 2 mA  | 70  | _    | 700  |      |
|                                      | h <sub>FE</sub> (2)        | V <sub>CE</sub> = 6 V, I <sub>C</sub> = 150 mA  | 25  | 100  | _    |      |
| Collector-emitter saturation voltage | V <sub>CE</sub> (sat)      | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$   | _   | 0.1  | 0.25 | V    |
| Base-emitter saturation voltage      | V <sub>BE</sub> (sat)      | $I_C = 100 \text{ mA}, I_B = 10 \text{ mA}$   | _   | _    | 1.0  | V    |
| Transition frequency                 | f <sub>T</sub>             | V <sub>CE</sub> = 10 V, I <sub>C</sub> = 1 mA   | 80  | _    | _    | MHz  |
| Collector output capacitance         | C <sub>ob</sub>            | V <sub>CB</sub> = 10 V, I <sub>E</sub> = 0, f = 1 MHz                                 | _   | 2.0  | 3.5  | pF   |
| Base intrinsic resistance            | r <sub>bb'</sub>           | $V_{CE} = 10 \text{ V}, I_{E} = -1 \text{ mA}$<br>f = 30 MHz                          | _   | 50   | _    | Ω    |
| Noise figure                         | NF                         | $V_{CE} = 6 \text{ V}, I_C = 0.1 \text{ mA}$<br>f = 1 kHz, $R_G = 10 \text{ k}\Omega$ | _   | 1.0  | 10   | dB   |

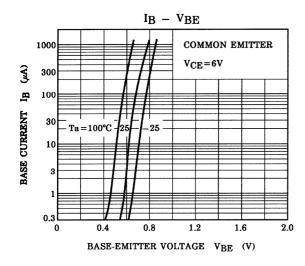
Note: hFE classification O: 70~140, Y: 120~240, GR: 200~400, BL: 350~700

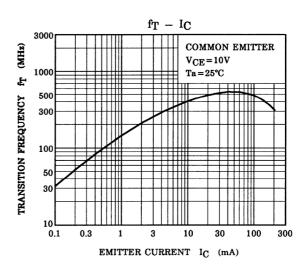


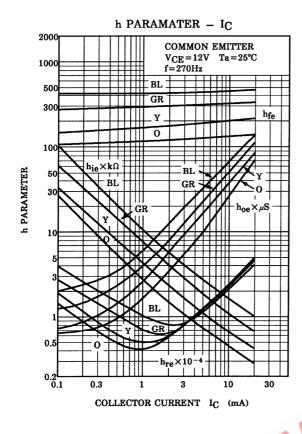


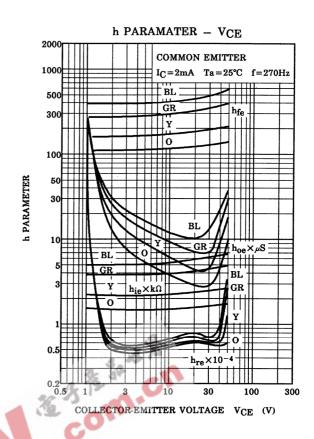


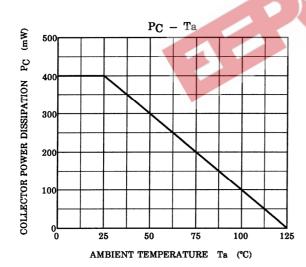












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20070701-EN GENERAL

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